Power MOSFET Single P-Channel SOT-23 -50 V, 10 Ω

- SOT-23 Surface Mount Package Saves Board Space
- AEC Q101 Qualified SBSS84LT1
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS ($T_J = 25^{\circ}C$ unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V_{DSS}	50	Vdc
Gate-to-Source Voltage - Continuous	V _{GS}	± 20	Vdc
Drain Current Continuous @ $T_A = 25^{\circ}C$ Pulsed Drain Current $(t_p \le 10 \ \mu s)$	I _D I _{DM}	130 520	mA
Total Power Dissipation @ T _A = 25°C	P _D	225	mW
Operating and Storage Temperature Range	T _J , T _{stg}	– 55 to 150	°C
Thermal Resistance – Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Maximum Lead Temperature for Soldering Purposes, for 10 seconds	T_L	260	°C

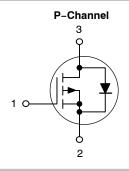
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



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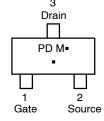
V _{(BR)DSS}	R _{DS(ON)} MAX		
–50 V	10 Ω @ 10 V		





SOT-23 CASE 318 STYLE 21

MARKING DIAGRAM & PIN ASSIGNMENT



PD = Specific Device Code

M = Date Code

= Pb-Free Package

(*Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
BSS84LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
SBSS84LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Ch	Symbol	Min	Тур	Max	Unit		
OFF CHARACTERISTICS				•	•		
Drain-to-Source Breakdown Volta (V _{GS} = 0 Vdc, I _D = -250 μAdc)	V _{(BR)DSS}	-50	_	_	Vdc		
Zero Gate Voltage Drain Current	I _{DSS}	- - -	- - -	-0.1 -15 -60	μAdc		
Gate-Body Leakage Current (V _{GS}	= \pm 20 Vdc, V_{DS} = 0 Vdc)	I _{GSS}	_	_	±10	nAdc	
ON CHARACTERISTICS (Note 1)							
Gate-Source Threaded Voltage (V	V _{GS(th)}	-0.9	-	-2.0	Vdc		
Static Drain-to-Source On-Resist	R _{DS(on)}	_	4.7	10	Ω		
Transfer Admittance (V _{DS} = −25 V	y _{fs}	50	-	-	mS		
DYNAMIC CHARACTERISTICS							
Input Capacitance	V _{DS} = 5.0 Vdc	C _{iss}	=	36	=	– pF	
Output Capacitance	V _{DS} = 5.0 Vdc	C _{oss}	=	17	-		
ansfer Capacitance V _{DG} = 5.0 Vdc		C _{rss}	-	6.5	-		
SWITCHING CHARACTERISTICS	6 (Note 2)						
Turn-On Delay Time		t _{d(on)}	-	3.6	_	ns	
Rise Time	V _{DD} = -15 Vdc, I _D = -2.5 Adc,	t _r	_	9.7	-		
Turn-Off Delay Time	R _L = 50 Ω	t _{d(off)}	_	12	-		
Fall Time		t _f	_	1.7	_		
Gate Charge	$V_{DD} = -40 \text{ Vdc}, I_D = -0.5 \text{ A}, V_{GS} = -10 \text{ V}$	Q _T	ı	2.2	-	nC	
SOURCE-DRAIN DIODE CHARA	CTERISTICS		_				
Continuous Current	I _S	-	_	-0.130	Α		
Pulsed Current	I _{SM}	-	-	-0.520			
orward Voltage (Note 2) $V_{GS} = 0 \text{ V, } I_S = -130 \text{ mA}$		V_{SD}	-	-	-2.2	V	

Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.

TYPICAL ELECTRICAL CHARACTERISTICS

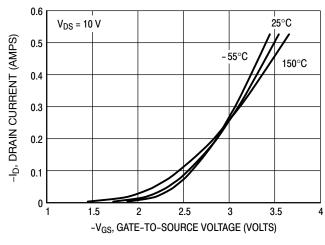


Figure 1. Transfer Characteristics

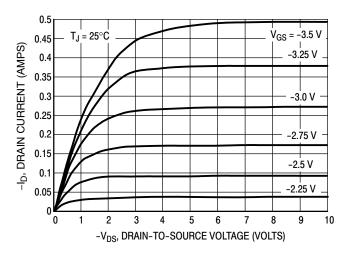
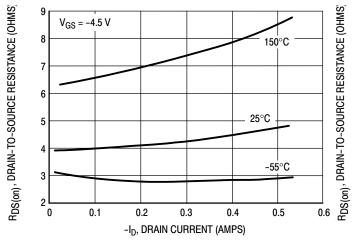


Figure 2. On-Region Characteristics

Switching characteristics are independent of operating junction temperature.

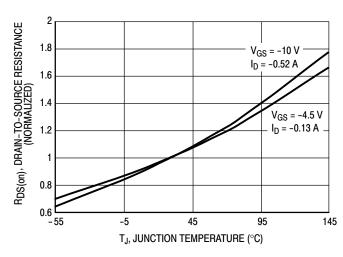
TYPICAL ELECTRICAL CHARACTERISTICS



150°C $V_{GS} = -10 \text{ V}$ 6.5 5.5 4.5 25°C 3.5 -55°Ċ 2.5 0 0.1 0.2 0.3 0.4 0.5 0.6 -ID, DRAIN CURRENT (AMPS)

Figure 3. On-Resistance versus Drain Current

Figure 4. On-Resistance versus Drain Current



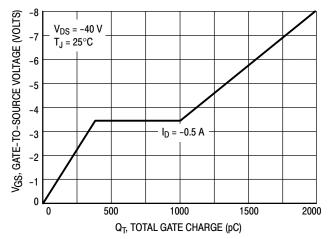


Figure 5. On-Resistance Variation with Temperature

Figure 6. Gate Charge

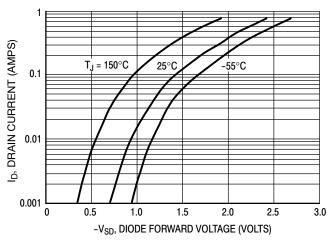
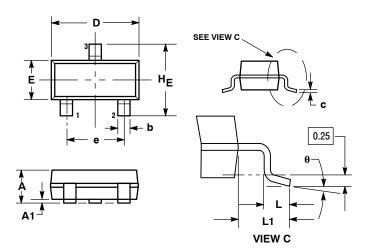


Figure 7. Body Diode Forward Voltage

PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AP**



NOTES:

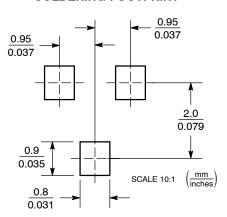
- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH
- CONTROLLING DIMENSION: INCH.
 MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH
 THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH,
- PROTRUSIONS, OR GATE BURRS

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	MAX	
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
С	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104
θ	0°		10°	0°	° 10	

STYLE 21: PIN 1. GATE

- SOURCE 2.
 - DRAIN

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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